ON Semiconductor

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MOSFET - Power, Single P-Channel

-40 V, 2.7 mΩ, -183 A

NVMFS3D0P04M8L

Features

- Low R_{DS(on)} to Minimize Conduction Losses
- High Current Capability
- Avalanche Energy Specified
- NVMFWS3D0P04M8L Wettable Flanks Product
- NVM Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

	.j _e e				-
Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	-40	V
Gate-to-Source Voltage			V _{GS}	± 20	V
Continuous Drain Cur-		$T_{C} = 25^{\circ}C$	۱ _D	-183	А
rent $R_{\theta JC}$ (Notes 1, 2, 3)	Steady State	$T_{C} = 100^{\circ}C$		-129	
Power Dissipation $R_{\theta JC}$		$T_{C} = 25^{\circ}C$	PD	171	W
(Notes 1, 2)		$T_{C} = 100^{\circ}C$		86	
Continuous Drain Cur-	Steady State	$T_A = 25^{\circ}C$	I _D	-28	А
rent $R_{\theta JA}$ (Notes 1, 2, 3)		$T_A = 100^{\circ}C$		-19	
Power Dissipation $R_{\theta JA}$		T _A = 25°C	PD	3.9	W
(Notes 1, 2)		$T_A = 100^{\circ}C$		1.9	
Pulsed Drain Current	T _A = 25°	C, t _p = 10 μs	I _{DM}	-900	А
Operating Junction and Storage Temperature Range			T _J , T _{stg}	−55 to +175	°C
Source Current (Body Diode)			۱ _S	-143	А
Single Pulse Drain-to-Source Avalanche Energy ($I_{L(pk)} = -30 \text{ A}$)			E _{AS}	752	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

MAXIMUM RATINGS (T₁ = 25° C unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State (Drain) (Note 2)	$R_{ extsf{ heta}JC}$	0.9	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	39	°C/W

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

2. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.

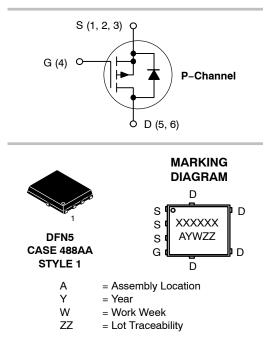
3. Continuous DC current rating. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.



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V _{(BR)DSS}	R _{DS(on)}	I _D
–40 V	2.7 m Ω @ –10 V	–183 A
	4.2 mΩ @ -4.5 V	- 100 A



ORDERING INFORMATION

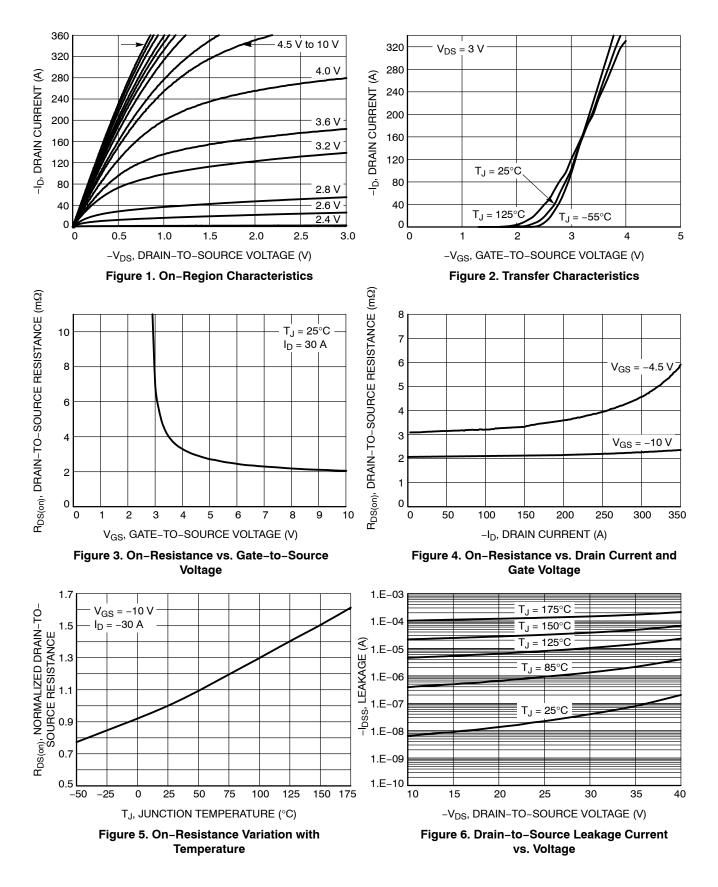
See detailed ordering, marking and shipping information on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = $25^{\circ}C$ unless otherwise noted)

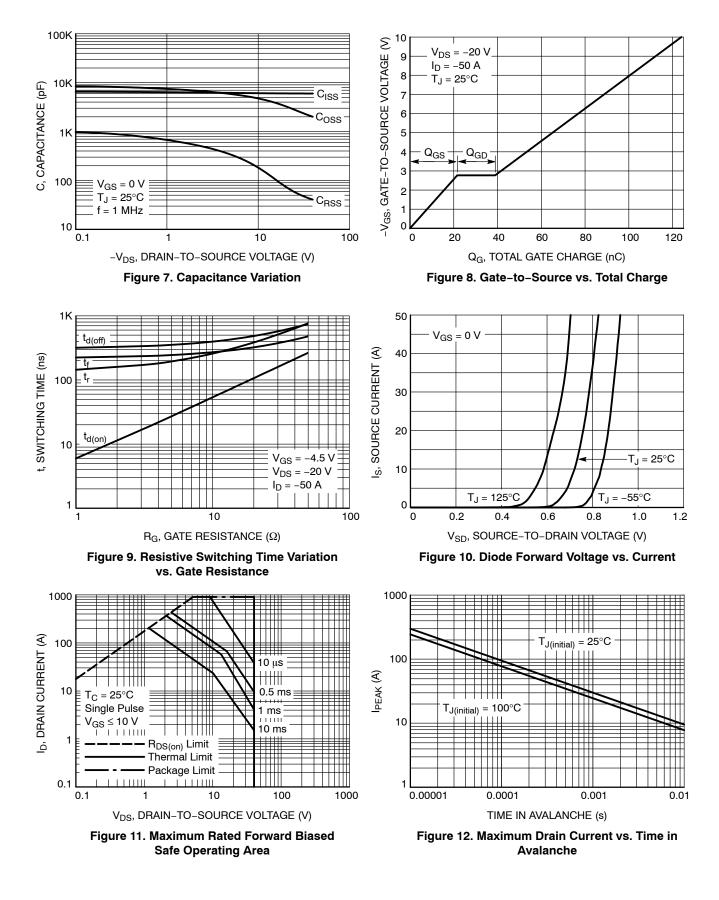
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = -250 μA		-40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				12		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = -40 V	T _J = 25°C T _J = 125°C			-1.0 -100	μΑ
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$				±100	nA
ON CHARACTERISTICS (Note 4)	400		5				
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$, $I_D = -2 \text{ mA}$		-1.0		-2.4	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J	· · · · · · · · · · · · · · · · · · ·			-4.7		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = -10 V, I _D = -30 A			2.1	2.7	mΩ
		V _{GS} = -4.5 V,	I _D = –15 A		3.1	4.2	1
Froward Transconductance	9 _{FS}	V _{DS} = -24 V, I _D = -50 A			205		S
CHARGES AND CAPACITANCES	· · · · · ·						
Input Capacitance	C _{iss}	V_{GS} = 0 V, f = 1.0 MHz, V_{DS} = -20 V			5827		pF
Output Capacitance	C _{oss}				3225		
Reverse Transfer Capacitance	C _{rss}				85.8		
Total Gate Charge	Q _{G(TOT)}	$V_{DS} = -20 \text{ V}, \qquad V_{GS} = -4.5 \text{ V}$ $I_{D} = -50 \text{ A} \qquad V_{GS} = -10 \text{ V}$	V _{GS} = -4.5 V		58.7		nC
				124		1	
Threshold Gate Charge	Q _{G(TH)}				10.9		1
Gate-to-Source Charge	Q _{GS}	V _{GS} = -10 V, V _I	-20 V.		21.6		1
Gate-to-Drain Charge	Q _{GD}	$I_{\rm D} = -50 \rm{A}$			17.3		
Plateau Voltage	V _{GP}				2.8		V
SWITCHING CHARACTERISTICS (No	otes 4)						
Turn-On Delay Time	t _{d(on)}				15.8		ns
Rise Time	t _r	VGS = -4.5 V. V	-20 V.		161		1
Turn-Off Delay Time	t _{d(off)}	V_{GS} = -4.5 V, V_{DS} = -20 V, I_{D} = -50 A, R_{G} = 2.5 Ω			349		1
Fall Time	t _f				256		1
DRAIN-SOURCE DIODE CHARACTE	RISTICS						
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 V,$ $I_{S} = -15 A$	$T_J = 25^{\circ}C$		-0.75	-1.20	V
			T _J = 125°C		-0.61		
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dl _s /dt = 100 A/µs, I _s = –50 A			113		ns
Charge Time	t _a				59.4		1
Discharge Time	t _b				53.1		1
Reverse Recovery Charge	Q _{RR}				246		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

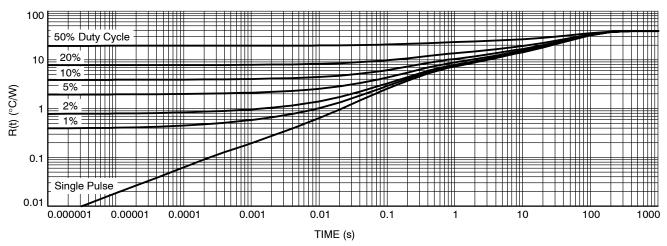


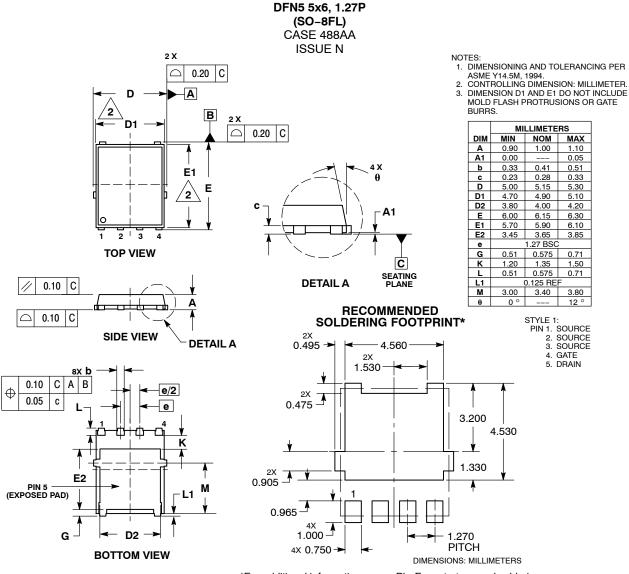
Figure 13. Thermal Response

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NVMFS3D0P04M8LT1G	3D0P04	DFN5 (Pb–Free)	1500 / Tape & Reel
NVMFWS3D0P04M8LT1G	3D0P4W	DFN5 (Pb–Free)	1500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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PUBLICATION ORDERING INFORMATION

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